

MiniSKiiP[®] 3

SKiiP 39AC12T4V1

Features

- Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for
- electrical connectionsUL recognised: File no. E63532

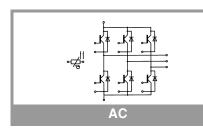
Typical Applications*

Inverter up to 50 kVA

Typical motor power 30 kW

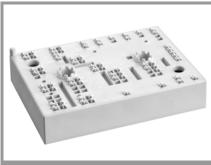
Remarks

- Max. case temperature limited to $T_C=125^{\circ}C$
- Product reliability results valid for $T_j \le 150^{\circ}C$ (recommended $T_{j,op} = -40...+150^{\circ}C$)
- For short circuit: Soft R_{Goff}
 recommended
- MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information.



Absolute	Maximum Rating	6		
Symbol	Conditions		Values	Unit
Inverter -	IGBT			
V _{CES}	T _j = 25 °C		1200	V
lc	λ_{paste} =0.8 W/(mK) T _j = 175 °C	T _s = 25 °C	167	А
		T _s = 70 °C	135	А
l _c	λ_{paste} =2.5 W/(mK) T _j = 175 °C	T _s = 25 °C	217	Α
		T _s = 70 °C	177	А
I _{Cnom}			150	А
I _{CRM}	I _{CRM} = 3 x I _{Cnom}		450	Α
V _{GES}			-20 20	V
t _{psc}	$V_{CC} = 800 V$ $V_{GE} \le 15 V$ $V_{CES} \le 1200 V$	T _j = 150 °C	10	μs
Tj			-40 175	°C
Inverse -	Diode			I
l _F	λ_{paste} =0.8 W/(mK) T _j = 175 °C	T _s = 25 °C	136	Α
		T _s = 70 °C	107	Α
	λ _{paste} =2.5 W/(mK)	T _s = 25 °C	163	Α
	T _j = 175 °C	T _s = 70 °C	130	Α
I _{Fnom}			150	Α
I _{FRM}	$I_{FRM} = 3 \times I_{Fnom}$		450	A
I _{FSM}	10 ms, sin 180°, T _j = 150 °C		900	А
Tj			-40 175	°C
Module				
I _{t(RMS)}	T _{terminal} = 80 °C, 20 A per spring		160	Α
T _{stg}			-40 125	°C
Visol	AC sinus 50 Hz, t = 1 min		2500	V
Characte	ristics			
Symbol	Conditions		min. typ. max	x. Unit
Inverter -	IGBT			

Inverter	- IGBT					
V _{CE(sat)}	I _C = 150 A	T _j = 25 °C		1.85	2.10	V
	V _{GE} = 15 V chiplevel	T _j = 150 °C		2.25	2.45	V
V _{CE0}	chiplevel	T _j = 25 °C		0.80	0.90	V
		T _j = 150 °C		0.70	0.80	V
r _{CE}	V _{GE} = 15 V chiplevel	T _j = 25 °C		7.0	8.0	mΩ
		T _j = 150 °C		10	11	mΩ
$V_{\text{GE(th)}}$	$V_{GE} = V_{CE}, I_C = 6 \text{ mA}$		5	5.8	6.5	V
I _{CES}	$V_{GE} = 0 V, V_{CE} = 12$	00 V, T _j = 25 °C		0.1	0.3	mA
Cies		f = 1 MHz		8.80		nF
Coes	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		0.58		nF
C _{res}		f = 1 MHz		0.47		nF
Q_{G}	- 8 V+ 15 V			850		nC
R _{Gint}	T _j = 25 °C			5.0		Ω
t _{d(on)}	$I_{\rm C} = 150 \rm{A}$	T _j = 150 °C		165		ns
t _r		T _j = 150 °C		50		ns
Eon		T _j = 150 °C		22.5		mJ
t _{d(off)}		T _j = 150 °C		390		ns
t _f		T _j = 150 °C		80		ns
E _{off}	V _{GE} = +15/-15 V	T _j = 150 °C		14		mJ
R _{th(j-s)}	per IGBT, λ _{paste} =0.8 W/(mK)			0.33		K/W
R _{th(j-s)}	per IGBT, λ _{paste} =2.5		0.21		K/W	



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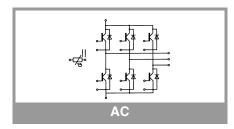
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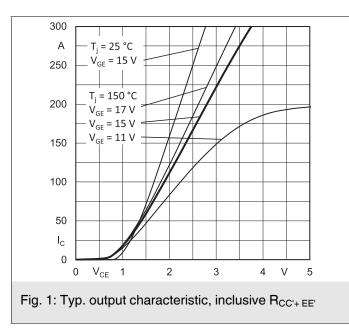
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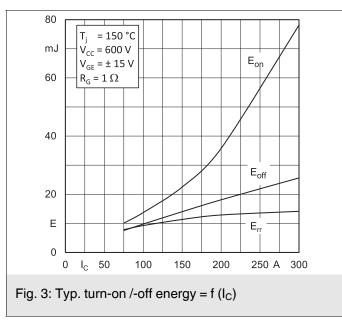
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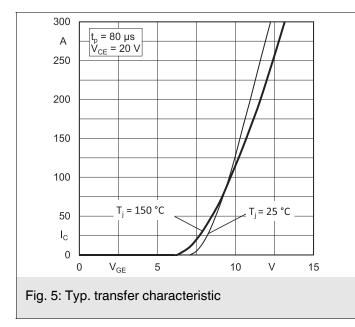
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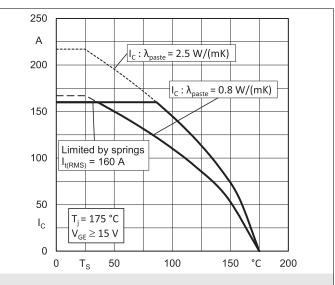
Characte	ristics					
Symbol	Conditions	min.	typ.	max.	Unit	
Inverse -	Diode					
$V_F = V_{EC}$	I _F = 150 A	T _j = 25 °C		2.14	2.46	V
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.07	2.38	V
V _{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V
		T _j = 150 °C		0.90	1.10	V
۲ _F	chiplevel	T _j = 25 °C		5.6	6.4	mΩ
		T _j = 150 °C		7.8	8.5	mΩ
I _{RRM}	I _F = 150 A di/dt _{off} = 4020 A/μs +15/-15	T _j = 150 °C		188		Α
Q _{rr}		T _j = 150 °C		27		μC
E _{rr}	$V_{CC} = 600 V$	T _j = 150 °C		11.4		mJ
R _{th(j-s)}	per Diode, λ _{paste} =0.8 W/(mK)			0.52		K/W
R _{th(j-s)}	per Diode, λ _{paste} =2.5 W/(mK)			0.39		K/W
Module	÷					
L _{CE}						nH
Ms	to heat sink		2		2.5	Nm
w				82		g
Temperat	ure Sensor					
R ₁₀₀	T _r =100°C (R ₂₅ =1000Ω)			1670 ± 3%		Ω
R(T)	R(T)=1000Ω[1+A(T], A = 7.635*10 ⁻³ °C B = 1.731*10 ⁻⁵ °C ⁻²	-25°C)+B(T-25°C) ² -1,				

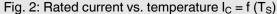


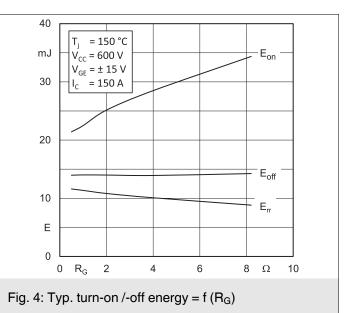


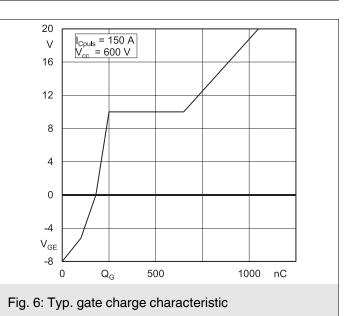


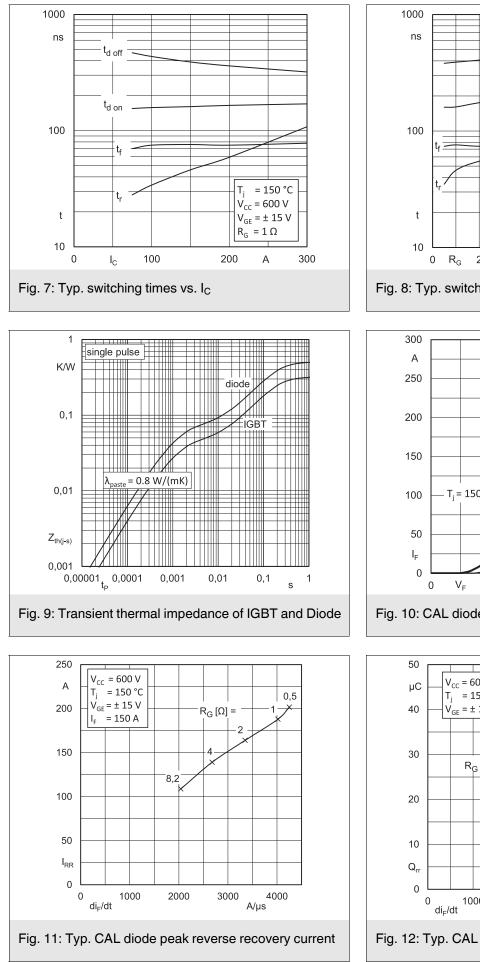


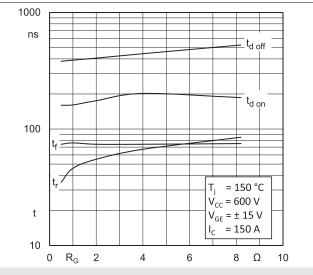














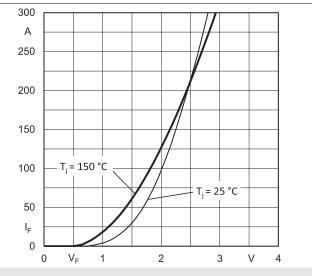
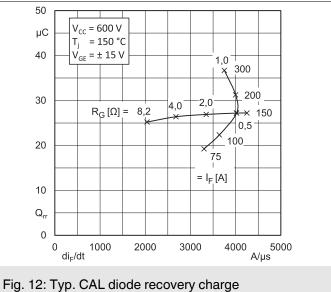
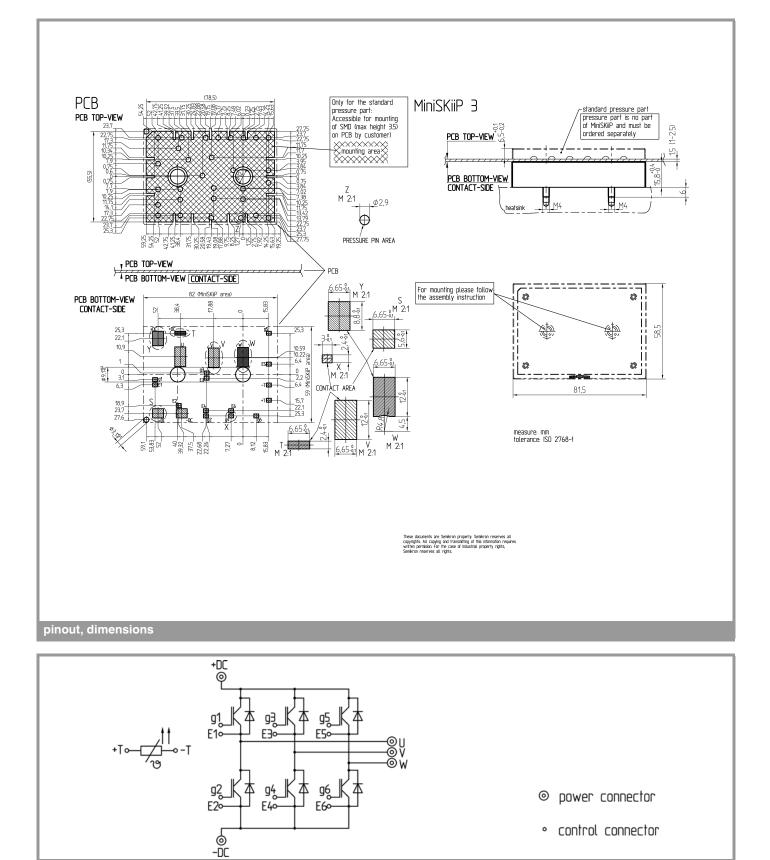


Fig. 10: CAL diode forward characteristic





pinout

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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 FP10R12W1T4_B11
 FP10R12YT3
 FP10R12YT3_B4
 FP150R07N3E4
 FP15R12KT3

 FP15R12W2T4
 F
 FF10R12W1T4_B11
 FF10R12YT3
 FF10R12YT3_B4
 FP15R12KT3